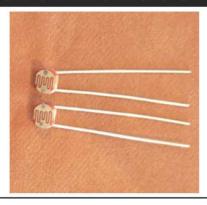
# **CdS PHOTOCONDUCTIVE CELLS**

## **GL5528**



▲ Epoxy encapsulated

▲ Quick response

▲ Small size

▲ High sensitivity

▲ Reliable performance

▲ Good characteristic of spectrum

Light Resistance at 10Lux (at 25°C)  $8\sim$ 20ΚΩ

Dark Resistance at 0 Lux 1.0MΩ(min)

Gamma value at 100-10Lux 0.7

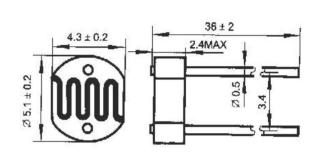
Power Dissipation(at 25°C) 100mW

Max Voltage (at 25°C) 150V

Spectral Response peak (at 25°C) 540nm

Ambient Temperature Range: - 30~+70℃

### Outline



#### **Measuring Conditions**

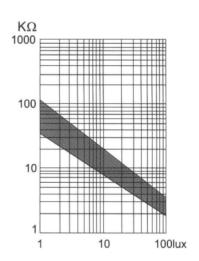
- Light Resistance: measured at 10 lux with standard light A (2854k color temperature) and 2h pre-illumination at 400-600 lux prior to testing.
- Dark Resistance: measured 10 seconds after pulsed 10 lux.
- Gamma Characteristic: between 10 lux and 100 lux and given by

$$T = \frac{\log (R10/R100)}{\log (100/10)} = \log (R10/R100)$$

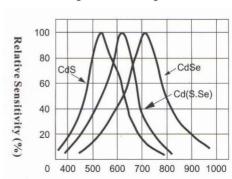
R10, R100 cell resistance at 10 lux and 100 lux. The error of T is  $\pm 0.1$ .

- Pmax: Max. power dissipation at ambient temperature of 25°C.
- Vmax: Max. voltage in darkness that may be applied to the cell continuously.

#### Illuminance Vs. Photo Resistance



#### **Spectral Response**



Wavelength (nm)